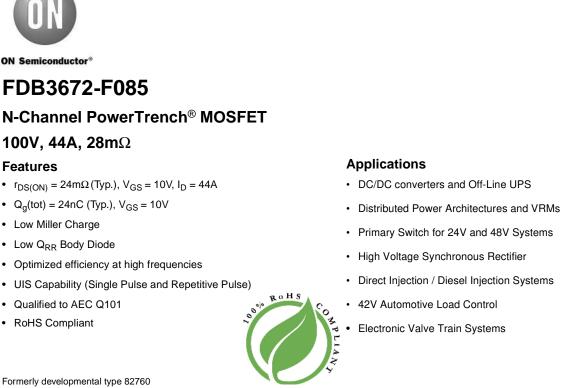
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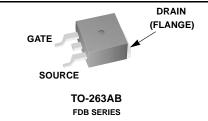
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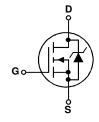




- Primary Switch for 24V and 48V Systems
- High Voltage Synchronous Rectifier
- Direct Injection / Diesel Injection Systems
- 42V Automotive Load Control
- Electronic Valve Train Systems

Formerly developmental type 82760

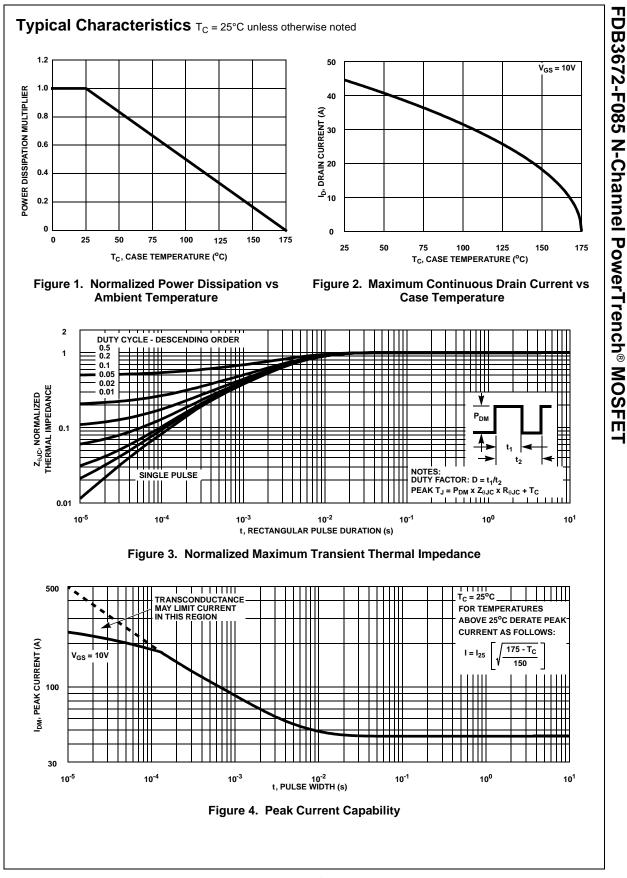




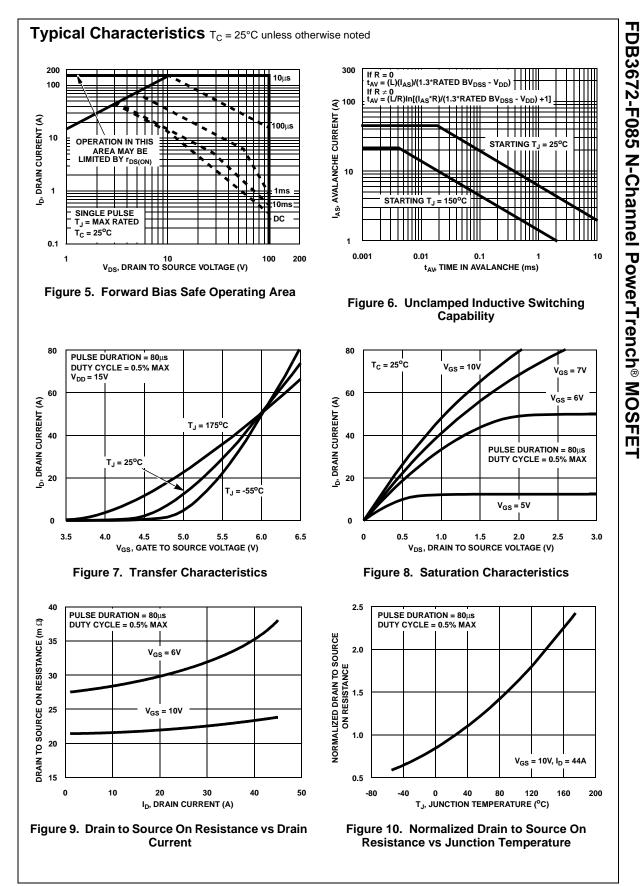
MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

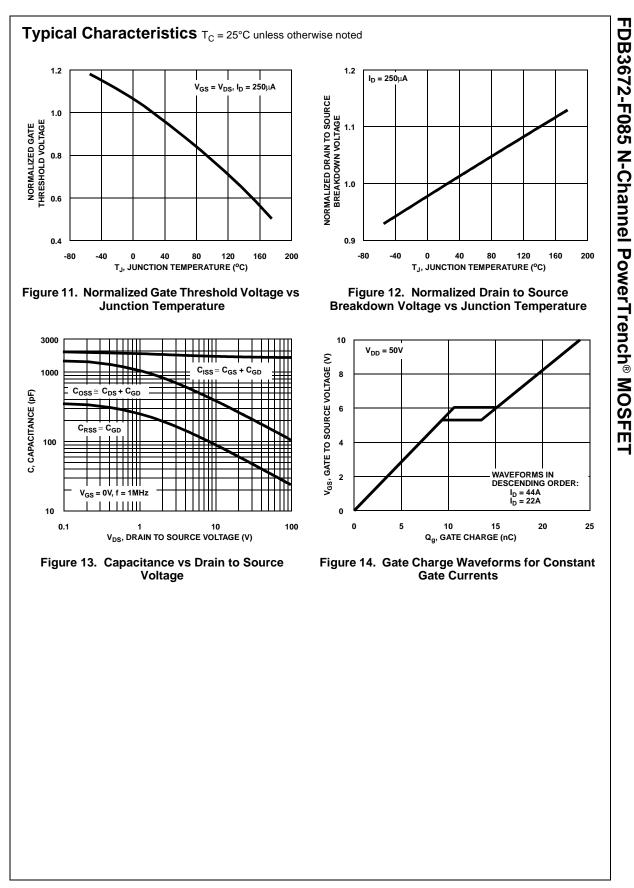
Symbol	Parameter	Ratings	Units	
V _{DSS}	Drain to Source Voltage	100	V	
V _{GS}	Gate to Source Voltage	±20	V	
Ι _D	Drain Current			
	Continuous (T _C = 25° C, V _{GS} = 10V)	44	А	
	Continuous ($T_C = 100^{\circ}C$, $V_{GS} = 10V$)	31	Α	
	Continuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$, $R_{\theta JA} = 43^{\circ}C/W$)	7.2	Α	
	Pulsed	Figure 4	Α	
E _{AS}	Single Pulse Avalanche Energy (Note 1)	120	mJ	
P _D	Power dissipation	120	W	
	Derate above 25°C	0.8	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature	-55 to 175	°C	
Therma	Characteristics			
$R_{\theta JC}$	Thermal Resistance Junction to Case TO-263	1.25	°C/W	
R _{θJA}	Thermal Resistance Junction to Ambient TO-263 (Note 2)	62	°C/W	
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-263, 1in ² copper pad area	43	°C/W	

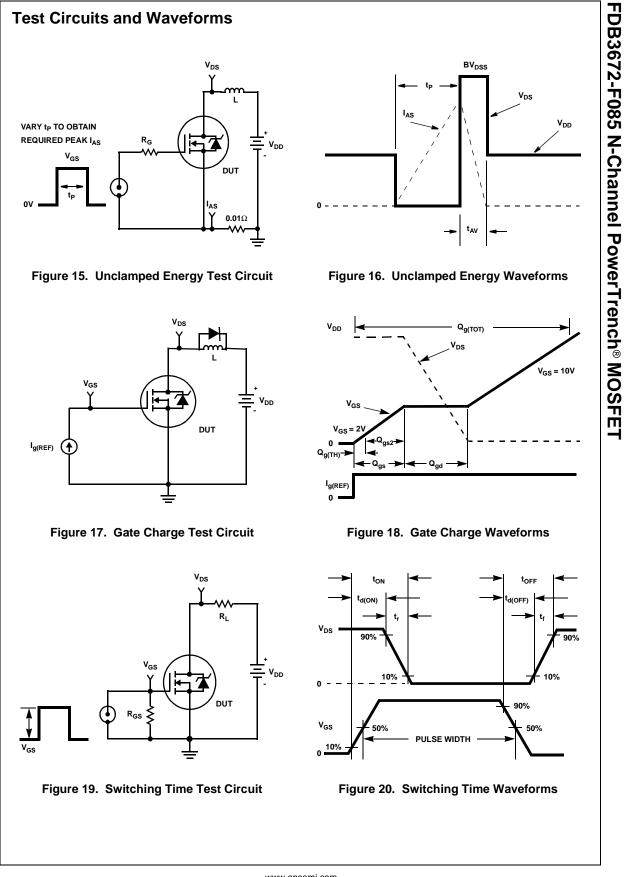
FDB3	Marking	Device	Package	Reel Size	Tape Width		Qua	Quantity	
	3672	FDB3672-F085	TO-263AB	TO-263AB 330mm		24mm		800 units	
LIECTLIC	al Chara	acteristics T _C = 25°C	C unless otherwi	se noted					
Symbol		Parameter		Conditions	Min	Тур	Max	Units	
Off Chara	cteristics	6							
B _{VDSS}	Drain to So	ource Breakdown Voltage	I _D = 250μA	$V_{GS} = 0V$	100	-	-	V	
	Zero Gate Voltage Drain Current		V _{DS} = 80V	$V_{DS} = 80V$ $V_{GS} = 0V$ $T_{C} = 150^{\circ}C$		-	1	1 250 μΑ	
IDSS						-	250		
I _{GSS}	Gate to So	ource Leakage Current	$V_{GS} = \pm 20 V$	1	-	-	±100	nA	
On Chara	cteristics	i							
V _{GS(TH)}	Gate to Source Threshold Voltage		$V_{GS} = V_{DS}$	$V_{GS} = V_{DS}, I_D = 250 \mu A$		-	4	V	
r _{DS(ON)}	Drain to Source On Resistance		I _D = 44A, V		-	0.024	0.028		
			I _D = 21A, V	$I_{\rm D} = 21$ A, $V_{\rm GS} = 6$ V,		0.031	0.047	Ω	
			I _D =44A, V _G	I _D =44A, V _{GS} =10V, T _C =175°C			0.068		
Dynamic	Characte	ristics							
C _{ISS}	Input Capa				-	1710	-	pF	
C _{OSS}	Output Ca		$V_{DS} = 25V,$	$V_{GS} = 0V,$	-	247	-	pF	
C _{RSS}		ransfer Capacitance	f = 1MHz		-	62	-	pF	
Q _{g(TOT)}		Charge at 10V	$V_{GS} = 0V to$	5 10V	-	24	31	nC	
Q _{g(TH)}		Gate Charge		$v_{DD} = 50V$	-	3.5	4.5	nC	
Q _{gs}		ource Gate Charge		I _D = 44A	-	11	-	nC	
Q _{gs2}		ge Threshold to Plateau		$I_g = 1.0 \text{mA}$	-	7.2	-	nC	
Q _{gd}		ain "Miller" Charge		-	-	4.5	-	nC	
	Switchin	g Characteristics (V	(1	
ton	Turn-On Ti	-	GS = 10V)		-	-	104	ns	
t _{d(ON)}	Turn-On D			 V _{DD} = 50V, I _D = 44A		11	-	ns	
t.	Rise Time		Vpp = 50V			59	-	ns	
t _{d(OFF)}	Turn-Off D		$V_{GS} = 10V, R_{GS} = 11.0\Omega$		-	26	-	ns	
t _f	Fall Time	,				44	-	ns	
t _{OFF}	Turn-Off Ti	ime				-	104	ns	
	uree Died	e Characteristics							
		e characteristics	I _{SD} = 44A		-	-	1.25	V	
V_{SD}	Source to Drain Diode Voltage	$I_{SD} = 44A$ $I_{SD} = 21A$		-	-	1.20	V		
- 30	Reverse R	ecovery Time	-	dl _{SD} /dt =100A/µs	-	-	52	ns	
t _{rr}		ecovered Charge	-	dl _{SD} /dt =100A/μs	-	-	80	nC	



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Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-252 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

ON Semiconductor provides thermal information to assist the designer's preliminary application evaluation. Figure 21

defines the $R_{\theta,JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the ON Semiconductor device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

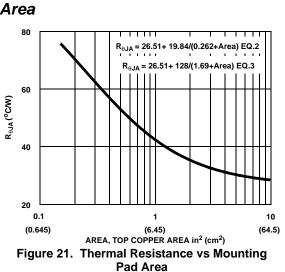
Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

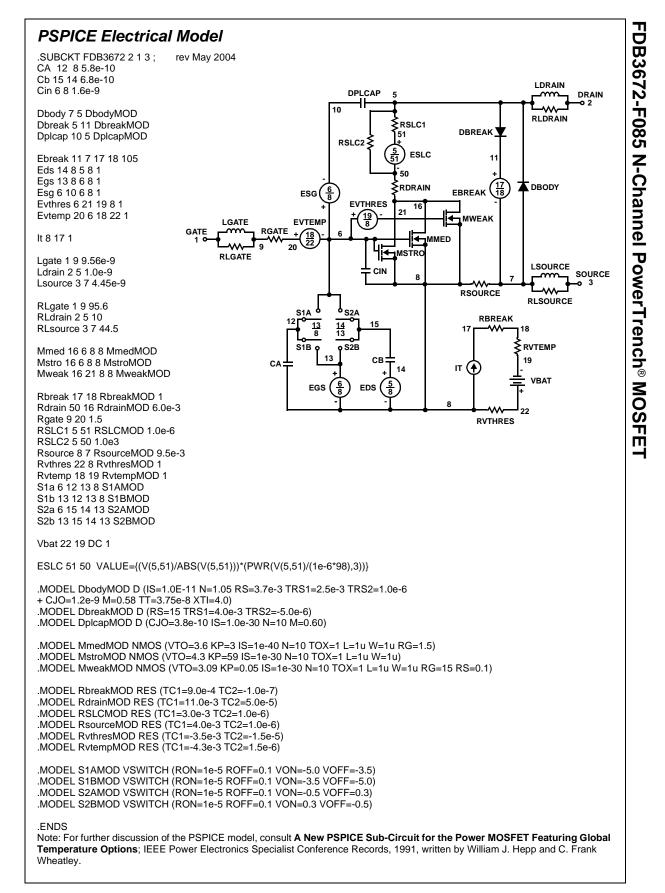
$$R_{\theta JA} = 26.51 + \frac{19.84}{(0.262 + Area)}$$
(EQ. 2)

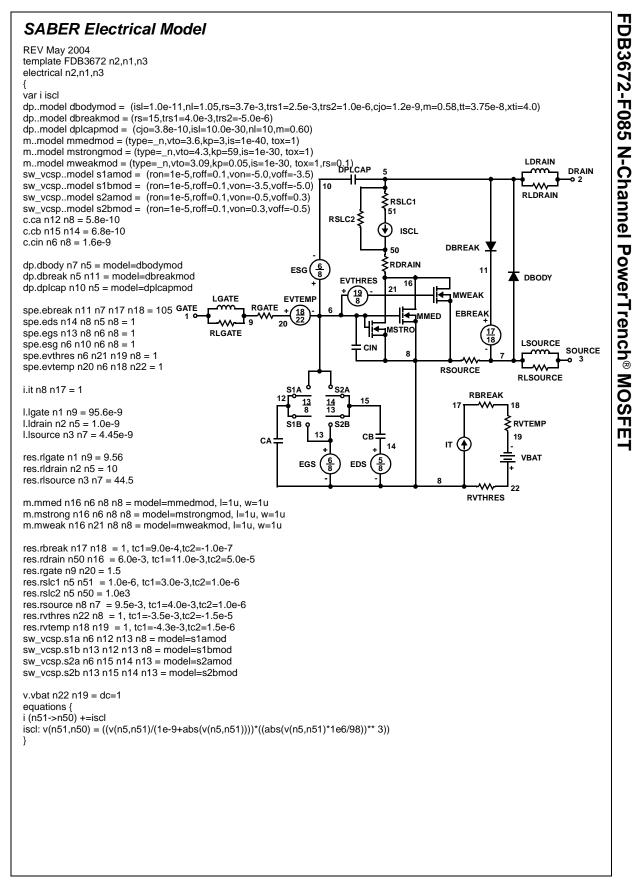
Area in Inches Squared

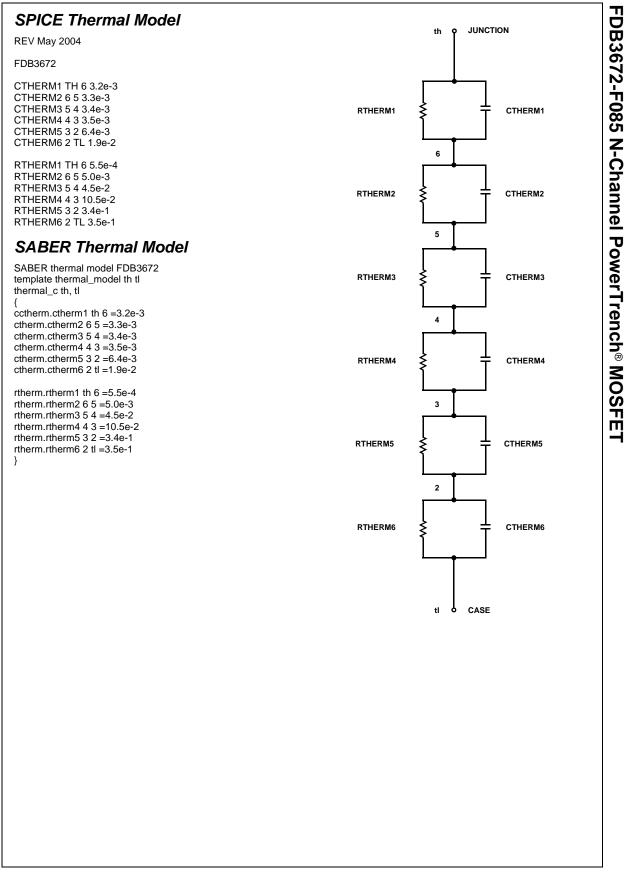
$$R_{\theta JA} = 26.51 + \frac{128}{(1.69 + Area)}$$
(EQ. 3)

Area in Centimeters Squared









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